²⁹Si NMR Characterization of α - and β -Silicon Nitride

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Abstract: Fine structure in the ²⁹Si MAS NMR spectra of Si₃N₄ has been observed, prompting a reevaluation of the current interpretation of Si₁N₄ spectra. On the basis of variable field studies, this fine structure indicates the presence of quadrupole-perturbed residual dipolar coupling to ¹⁴N. This is apparently the first such observation in ²⁹Si NMR. The peaks in the spectra of α - and β -Si₃N₄ are shown to arise from differences in the non-nearest-neighbor environments. Arguments based on a "sphere of influence" approach appear to be an attractive interpretive tool for these and similar ceramic materials. Some speculation is also presented concerning the relationship between the ²⁹Si-¹⁴N splitting and the structure of Si₃N₄. The magnetic field dependence of Si₁N₄ spectra emphasizes the point that high fields are important in the study of ceramics, even for nuclides that are spin 1/2.

High-performance ceramics are an important class of engineered materials due to their excellent mechanical and thermal properties. Among the most important of these is silicon nitride (Si₃N₄). Si₃N₄ ceramics exhibit high strength at high temperatures, good thermal stress resistance, and relatively good resistance to oxidation. Efforts to optimize these properties have largely centered on advanced processing techniques. However, the need to relate performance with atomic level chemistry and structure is becoming increasingly important.²

Solid-state NMR has proven to be both powerful and versatile in the characterization of ceramic materials.³⁻⁵ NMR is capable of identifying crystalline and amorphous phases, determining the structure of such phases, and studying the chemistry of these phases at the atomic level. For example, early ²⁹Si NMR studies of Si₃N₄ revealed that NMR can readily distinguish the crystalline forms, 6,7 accurately quantitate the amorphous content,7 and monitor the effects of sintering.8

One of the most attractive features of NMR is its sensitivity to the local environment about the nucleus being observed. The most common NMR parameter indicative of this sensitivity is chemical shift. As a result, a number of correlations⁹⁻¹⁷ between chemical shift and structural features such as bond angle⁹⁻¹² and type of nearest¹³⁻¹⁵ and non-nearest-neighbor environments¹⁷ have been derived for solid inorganic systems. The sensitivity of NMR to local structure, however, is not merely limited to chemical shift effects. In fact, subtle structural details are also available in NMR data such as spin-spin couplings and relaxation phenomena. For example, when a spin 1/2 nucleus experiences dipolar coupling to a quadrupolar nucleus, an NMR line splitting is observed. The size of this splitting is dependent upon, among other things, the distance between the two nuclei. 18,19 Detailed analyses of NMR data such as chemical shift and coupling constants hold considerable promise for the structural analysis of new ceramic phases and amorphous systems.

The purpose of this paper is to present a detailed examination of α - and β -Si₃N₄ by ²⁹Si NMR, including the first reported observation of ²⁹Si⁻¹⁴N residual dipolar coupling. This observation has prompted a reevaluation of the current spectral interpretation of Si₃N₄ and has suggested an attractive interpretive tool for the NMR characterization of ceramic phases. Finally, this work demonstrates the need to study many ceramic systems, including spin 1/2 nuclides, at high magnetic fields.

Experimental Section

Silicon-29 NMR spectra were acquired under magic-angle spinning (MAS)²⁰⁻²² conditions with single 70-90° pulses and pulse delays of 1

h. Pulse delays of 1 h were required to ensure total magnetization recovery and, therefore, accurate quantitative data.7 All spectra were externally referenced relative to TMS at 0 ppm. The spectra presented in the text were acquired on a Varian XL200 (39.6 MHz), a Chemagnetics CMX 300 (59.5 MHz), and a Bruker MSL400 (79.5 MHz). The sample of α -Si₃N₄ was a previously studied,⁷ commercially available powder (GTE SN502). The sample of β -Si₃N₄ was also a comercially available powder (UBE SNWB). The 79.5-MHz spectra presented in Figures 2 and 3 were digitally manipulated with a 5-Hz resolution enhancement. This was done to reveal more effectively the nature of the fine structure and resulted in a negligible decrease in signal to noise and no additional peaks. The spectra presented in Figure 1 were digitally manipulated with 10-20-Hz exponential line broadening, as has been used in the past.7

Background

There are two crystalline forms of silicon nitride, α and β . ^{23–26} The α phase is converted to β during liquid-phase sintering. In both structures each silicon is tetrahedrally bound to four nitrogens. In addition, both structures consist of interleaved sheets of 8- and 12-membered rings of silicon and nitrogen. In the α form, each alternate sheet is inverted and offset slightly with respect to the underlying sheet, creating two crystallographically unique silicon

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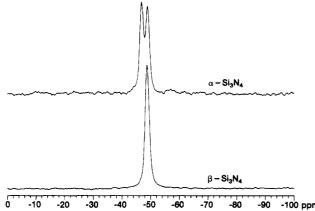


Figure 1. ²⁹Si MAS NMR spectra of α - and β -Si₃N₄ obtained at 59.5 MHz (300-MHz ¹H frequency).

sites. $^{23-26}$ A 29 Si NMR spectrum of α -Si₃N₄, obtained at 59.5 MHz (300-MHz 1 H frequency), is given in Figure 1. The spectrum consists of two peaks centered at roughly $^{-46.8}$ and $^{-48.9}$ ppm. Early 29 Si NMR studies $^{5-9}$ of α -Si₃N₄ have assigned these two peaks to the presence of mixtures or to slight differences in the SiN₄ tetrahedra.

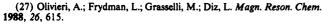
In the β form of silicon nitride, the interleaved sheets of Si and N are stacked in a regular manner. The result is that there is only one unique Si site. ²³⁻²⁶ As can be seen in Figure 1, there is only one peak in the ²⁹Si NMR spectrum of β -Si₃N₄ with a ²⁹Si chemical shift of roughly -48.7 ppm. Note that the chemical shifts for the α and β structures are similar, reflecting the similarities in nuclear environment.

Observation of Fine Structure

As discussed above, the ²⁹Si MAS NMR spectrum of α -silicon nitride (α-Si₃N₄) contains two major peaks. However, a careful and thorough analysis of the NMR data reveals that the two main peaks of the α -Si₃N₄ spectrum show additional fine structure. ²⁹Si MAS NMR spectra of α-Si₃N₄ obtained at three fields are given in Figure 2. The three fields used in this study are 39.6 MHz (200-MHz ¹H frequency), 59.5 MHz (300-MHz ¹H frequency), and 79.5 MHz (400-MHz 1H frequency). The spectra presented in Figure 2 (and Figure 3) represent high signal-to-noise data with no digitally added line broadening. Note the existence of substantial fine structure. At 39.6 MHz, this fine structure effectively eliminates the distinction between the major resonances. One potential explanation for the fine structure is the presence of microdomains that have the effect of slightly shifting the isotropic resonance. If this were the case, each spectrum would represent a superposition of spectra from four or five different microdomains. In addition, the position of the lines would be field independent since they would result from a "chemical shift" effect. However, a detailed comparison of the spectra in Figure 2 reveals a field dependence. This is best seen by comparing the downfield region where the resolution is the greatest. With use of only the resolved downfield peaks, the splitting was found to be 32 Hz at 39.6 MHz,

29 Hz at 59.5 MHz, and 24 Hz at 79.5 MHz.

Magic-angle spinning²⁰⁻²² is widely applied in solid-state NMR to remove sources of inhomogeneous line broadening such as chemical shift anisotropy, heteronuclear dipolar coupling, and first-order quadrupolar effects. This technique is often not entirely efficient. A common example occurs with a spin $^{1}/_{2}$ nucleus experiences dipolar coupling to a quadrupolar nucleus. The failure of MAS to remove this interaction is related to the introduction of geometrical factors other than $(\theta - 1)$, for which the magic angle is no longer "magic". Residual dipolar coupling is field-dependent and scales inversely with respect to field strength. 18,19 The most common example is for a 13 C adjacent to nitrogen. $^{18,19,27-35}$ In



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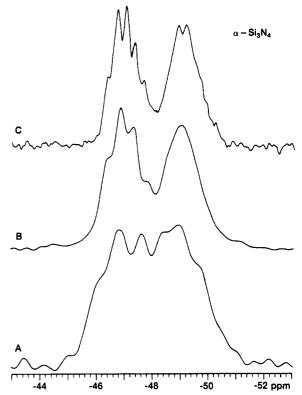


Figure 2. ²⁹Si MAS NMR spectra of α -Si₃N₄ obtained at (A) 39.5, (B) 59.5, and (C) 79.5 MHz (200-, 300-, and 400-MHz ¹H frequency).

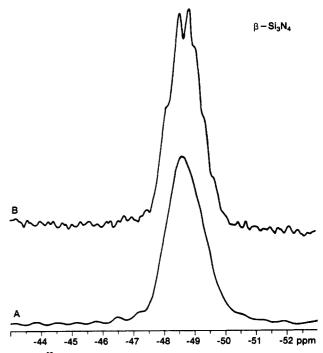


Figure 3. 29 Si MAS NMR spectra of β -Si₃N₄ obtained at (A) 59.5 and (B) 79.5 MHz (300- and 400-MHz 1 H frequency).

general, the ¹⁴N effect typically broadens the NMR line or creates an asymmetry. However, distinct resolvable splittings are observed,

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for example, in crystalline small organic molecules and peptides. If the fine structure observed in Figure 2 is due to ²⁹Si-¹⁴N residual quadrupole-perturbed dipolar coupling, then the size of the splitting should be inversely proportional to field strength. 18,19 An examination of the data reveals that the correlation between the splitting at 79.5 MHz (24 Hz) and 59.5 MHz (29 Hz) provides a reasonable fit. The splitting at 39.6 MHz (32 Hz), however, does not correlate as well. In α -Si₃N₄ each ²⁹Si is tetrahedrally bound to four ¹⁴N, resulting in a complex splitting pattern. This pattern is expected to contain as many as 16 lines depending on the size and sign of the coupling, as well as potential peak overlap. 18 Thus, the ²⁹Si NMR spectrum of α-Si₃N₄ containing quadrupole-perturbed residual dipolar coupling is expected to be a superposition of 32 lines. In addition, some scalar J coupling may also be present. As a result, the measured splittings may be complicated, especially at 39.6 MHz where overlap is expected to be the most severe. In spite of this limitation, it is reasonable to attribute the changes in fine structure to the presence of residual dipolar coupling to 14N for two reasons: (1) the expected dominance of this interaction for a Si tetrahedrally bound to four nitrogens and (2) the observed spectral changes with varying field strength (Figures 2 and 3), especially between 59.5 and 79.5 MHz. While the effects of residual dipolar coupling to quadrupolar nuclides have been extensively observed for ¹³C in organic systems, 18,19,27-35 similar effects for other spin 1/2 nuclides have only been rarely reported.³⁶⁻³⁸ This appears to be the first for ²⁹Si.

A more detailed examination of the ²⁹Si NMR spectrum of β-Si₃N₄ reveals a nonsymmetric line shape at 59.5 MHz and a clear splitting at 79.5 MHz. This is illustrated in the spectra given in Figure 3. The splitting observed at 79.5 MHz was found to be 24 Hz. Unfortunately, it was not possible to obtain a similar spectrum at 39.6 MHz. Because of the strong structural similarities between the α and β forms, it is reasonable to attribute the observed changes in splitting and line shape to the presence

of ²⁹Si-¹⁴N residual dipolar coupling.

The observation of residual ²⁹Si-¹⁴N dipolar coupling in the $^{29}\text{Si MAS NMR}$ spectra of α - and β -Si $_3\bar{\text{N}}_4$ has important implications for the study of ceramic systems by NMR. As seen in Figure 2, this coupling can effectively remove desired resolution among the chemically inequivalent sites in spectra acquired at too low a field. On the basis of the data presented here, at least a 59.5-MHz operating frequency appears to be necessary to maintain discrimination among different sites in Si/N ceramic materials. The drive toward higher fields for analysis of ceramic materials can thus be justified on three grounds: increased sensitivity, reduction of quadrupolar effects even for nonquadrupolar nuclides, and an increased spread in chemical shift for discrimination among different sites.

Interpretation of Si₃N₄ Spectra

The ²⁹Si NMR spectrum of highly crystalline silicon nitride can be considered as a superposition of three major chemically shifted lines: two from the α phase and one from the β phase. On the surface, one can easily account for the number of observed peaks on the basis of the number of crystallographically distinct sites. However, a more thorough investigation is required to explain the spectra in terms of local Si environments and to account for the differences between the α and β forms. Such an understanding is pivotal for future studies of related systems and of the effects of processing on Si₃N₄ local atomic structure.

For the purpose of this discussion, the two unique Si sites in $\alpha\text{-}Si_3N_4$ will be referred to as $Si\alpha 1$ and $Si\alpha 2$ (from the identities given in ref 24). The unique site in β -Si₃N₄ will be simply referred to as Sis. Consider first, the two-peak pattern observed for α-Si₃N₄. Previous studies^{6,7} have attributed this pattern to small

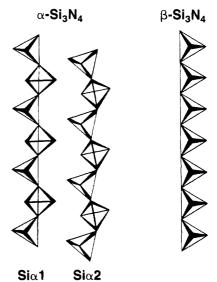


Figure 4. Schematic representation of the SiN_4 tetrahedra stacking sequences in α - and β -Si₃N₄.

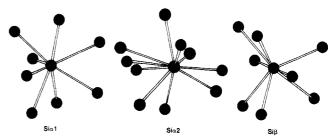


Figure 5. Schematic representation of the neighboring silicon environments for each silicon type in α - and β -Si₃N₄ within 3.80-Å sphere of influence (see text).

differences in the SiN₄ tetrahedra between Si α 1 and Si α 2. For example, the average Si-N bond length is 1.747 Å at Si α 1 and 1.740 Å at $Si\alpha 2$. With this argument, the chemical shift differences would arise from a spatial difference of only 0.007 Å. This difference is probably not significant since it is smaller than the error limits of even the most careful X-ray structure determination. In addition, the average Si-N bond length in α -Si₃N₄ is 1.732 Å. If bond length was the dominant chemical shift determining interaction, then we would not expect to find the $Si\beta$ (1.728 Å) peak coincident with one of the two α -Si₃N₄ (1.740, 1.747 Å) resonances, as observed in Figure 1. Similar arguments can also be used to eliminate average bond angle from consideration. In light of these simple discrepancies, we were led to find alternative chemical shift interpretations based on non-nearestneighbor environments.

Since each silicon in both phases is tetrahedrally bound to four nitrogens, it is reasonable to assume that any differences in non-nearest-neighbor environment would be related to the arrangement of surrounding silicon nuclei. This is, in fact, the case. In β -Si₃N₄, the SiN₄ tetrahedra are oriented such that the edges are in a straight line parallel to the unit cell c axis. In α -Si₃N₄, there are two types of stacking sequences that are distorted with respect to one another by about $60-70^{\circ}$ around the c axis. Schematic representations of the SiN₄ tetrahedra stacking sequences in α - and β -Si₃N₄ are given in Figure 4. One can see, by inspection, that the surrounding network is different for $Si\alpha 1$, $Si\alpha 2$, and $Si\beta$.

Using figures such as these and the available crystallographic data,23-26 we find that all three silicon types have eight Si neighbors within a sphere of 3.00 \pm 0.12 Å. For Sial and Si\beta, the next nearest silicon neighbor(s) resides at an outer surface of 3.80 ± 0.07 Å. The Si α 2 nucleus also has a neighbor residing on the 3.80-Å surface. However, between the 3.00- and 3.80-Å surfaces are two additional silicon neighbors at 3.60 Å. These additional neighbors are absent for the cases of $Si\alpha 1$ and $Si\beta$. Thus, within

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a 3.80-Å "sphere of influence", Si α 1 and Si β have eight neighboring silicons while $Si\alpha 2$ has ten.

The silicon environments within the 3.8-Å sphere of influence for each silicon type are illustrated in Figure 5. The fact that $Si\alpha 1$ has eight neighbors and $Si\alpha 2$ has ten can be used to explain the two-peak spectrum shown in Figure 1. Using the above argument, we would expect the chemical shifts of Si β and Si α 1 to be the same, since they both have eight silicon neighbors. In fact, the $Si\beta$ peak (-48.7 ppm) is virtually coincident with one of the two α -Si₃N₄ peaks (-46.8, -48.9 ppm). Thus, we are led to the conclusion that in α -Si₃N₄ the peak at -48.9 ppm can be assigned to $Si\alpha 1$ and the peak at -46.8 ppm to $Si\alpha 2$. The sphere of influence approach outlined above has resulted in the first chemical shift assignments for α - and β -Si₃N₄.

Residual Dipolar Coupling

It is beyond the scope of this work to present a detailed analysis of the observed ²⁹Si-¹⁴N residual dipolar coupling in terms of the structure of Si₃N₄. However, some brief comments are worthy of note at this time. With the same formalism previously ¹⁸ adopted for an isolated ¹³C-¹⁴N pair, the size of the splitting (S) is given by

$$S = \frac{9}{20}(DX/Z_{\rm N})[(3\cos^2(\beta - 1)) + \eta\sin^2\beta\cos 2\alpha] \quad (1)$$

Here, D is the dipolar coupling constant, X is the quadrupole coupling constant, Z_N is the Zeeman frequency of ¹⁴N in the applied field, and η is the asymmetry parameter of the electric field gradient (EFG) tensor. β and α are the polar and azimuthal angles that define the orientation of the internuclear vector in the principal axis system of the EFG at the ¹⁴N nucleus with respect to the direction of B_0 . The dipolar coupling constant (D) is inversely proportional to the cube of the Si-N internuclear distance, r

In Si₃N₄, each ²⁹Si experiences the effect of four ¹⁴N nuclei, with the result of substantially complicating eq 1. However, one should note that the size of the splitting depends upon geometric (β, α, r) and energetic (X, η, Z_N) factors. To a first approximation, it seems reasonable to assume that the energetic factors $(X, \eta,$ $Z_{\rm N}$) are equivalent or similar at Si α 1, Si α 2, and Si β for a given applied magnetic field, since the values for X and η should be dominated by interactions associated with the SiN₄ tetrahedra and Z_N is constant. This being the case, then differences in the splitting between $\mathrm{Si}\alpha 1$, $\mathrm{Si}\alpha 2$, and $\mathrm{Si}\beta$ would be due solely to differences in geometric factors. With this information, it may be possible refine the structural details of Si₃N₄. This type of analysis has been very successful in organic systems, ^{18,19,27,30,32-34} and work along these lines for Si₃N₄ is underway.

Two intriguing observations suggest that such an analysis would provide unique and detailed information. As we have shown above, the chemical shift of $Si\alpha 2$ (-46.8 ppm) is distinct from that of $Si\alpha 1$ (-48.9 ppm) and $Si\beta$ (-48.7 ppm). In terms of chemical shift, $Si\alpha 1$ and $Si\beta$ form a pair. However, in considering the size of the splitting determined by the separation between maxima at 79.5 MHz, we find that $Si\alpha 2$ (24 Hz) and $Si\beta$ (24 Hz) form a pair, while Siα1 (20 Hz) remains distinct. This suggests that the Si-N geometric factors are similar for Si α 2 and Si β but distinct from those for $Si\alpha 1$. The second intriguing observation concerns

the apparent line width of the "unique" resonances in these spectra. The apparent line width of the three major resonances for $Si\alpha 1$, $Si\alpha 2$, and $Si\beta$ is not the same at a given field. For example, by comparing the line width of the major resonances at 79.5 MHz in Figures 2 and 3, one can see that the resonance for $Si\beta$ is the narrowest. Subtleties in splittings, peak positions, and line width have the clear potential to provide unique structural information in Si₃N₄ systems.

Finally, it should be noted that the data in Figures 2 and 3 can also be used to provide a rough estimate of the quadrupolar coupling constant. On the basis of the data obtained at 79.5 MHz, we find an estimate for X to be 0.23 MHz.

Sphere of Influence

The chemical shift assignments for α - and β -Si₃N₄ were determined above from a sphere of influence approach. By examining the non-nearest-neighbor network surrounding each silicon site, we were able to identify the sphere of influence that gave rise to different chemical shifts for nuclei with identical neighbors. It should be noted that a similar approach has also proven successful in the related highly refactory ceramics, LaSi₃N₅ and SiC. In a separate study, Hatfield and co-workers have shown³⁹ that this sphere of influence is roughly 4 Å in LaSi₃N₅. Hartman and co-workers^{40,41} have shown that the sphere of influence in SiC is roughly 5 Å. In this study, the sphere about Si_3N_4 is 3.8 Å. These examples emphasize two important points. The first is that a sphere of influence approach is an attractive interpretive tool for the characterization of ceramic materials containing nuclei with equivalent nearest neighbors. The second, and perhaps more important point, is that in some ceramic materials ²⁹Si chemical shifts can be sensitive to influences as far away as 5 Å. This has major implications for examining the local effects induced by technologically significant forces such as thermal and mechanical

Conclusions

The features in the ²⁹Si NMR spectra of α - and β -silicon nitride have been shown to arise from a combination of non-nearestneighbor effects and the presence of residual quadrupole-perturbed dipolar coupling. The NMR results offer a detailed and selfconsistent characterization of these technologically important materials and help lay the groundwork for future studies of new ceramic systems. The observation of non-nearest-neighbor-induced chemical shift differences also reveals that ²⁹Si NMR can be used to monitor structural changes on the order of 5 Å.

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